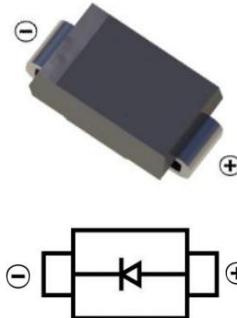


SMA General Purpose High Voltage Rectifier Diode 通用高压整流二极管**■Features 特点**

Low reverse leakage current 低反向漏电流
 High surge current capability 高浪涌电流能力
 Built-in strain relief 内应力释放
 Surface mount device 表面贴装器件
 Case 封装:SMA

**■Maximum Rating 最大额定值**

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	GS1Y	GS1Z	Unit 单位
Peak Reverse Voltage 反向峰值电压	V _{RRM}	1600	2000	V
DC Reverse Voltage 直流反向电压	V _R	1600	2000	V
RMS Reverse Voltage 反向电压均方根值	V _{R(RMS)}	1120	1400	V
Forward Rectified Current 正向整流电流	I _F	1.5		A
Peak Surge Current 峰值浪涌电流	I _{FSM}	30		A
Thermal Resistance J-A 结到环境热阻	R _{θJA}	95		°C/W
Junction and Storage Temperature 结温和储藏温度	T _{J,T_{stg}}	150°C,-55to+150°C		

■Electrical Characteristics 电特性

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Typ 典型值	Max 最大值	Unit 单位	Test Condition 测试条件
Forward Voltage 正向电压	V _F			1.15	V	I _F =1.5A
Reverse Current(T _A =25°C)/ 反向电流(T _A =125°C/)	I _R			5 50	uA	V _R =V _{RRM}
Diode Capacitance 二极管电容	C _D		20		pF	V _R =4V,f=1MHz

■Typical Characteristic Curve 典型特性曲线

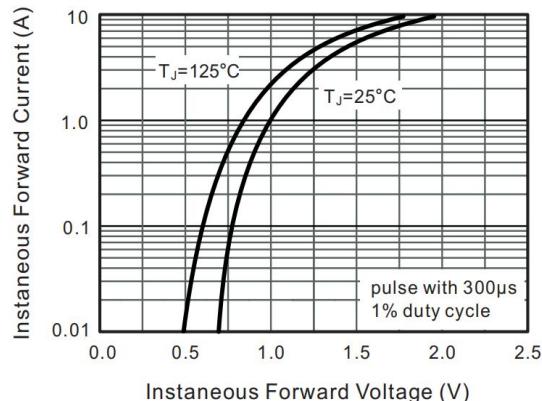


Figure 1: Forward Characteristics

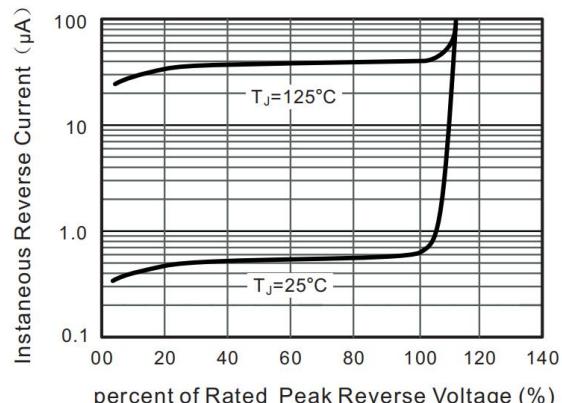


Figure 2: Reverse Characteristics

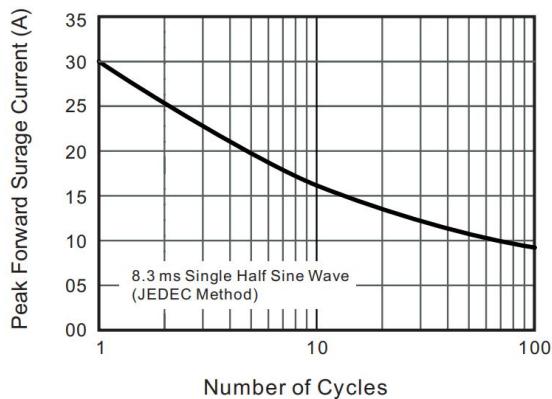


Figure 3: Surge Current Characteristics

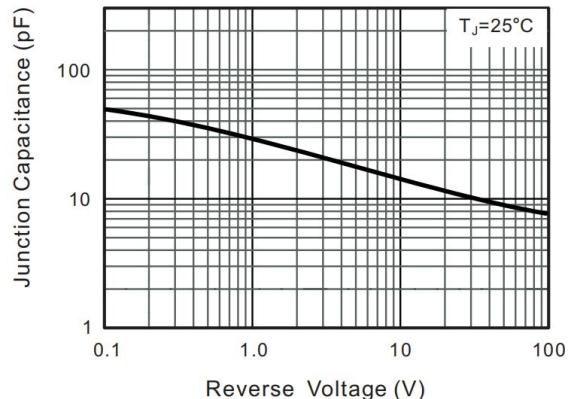


Figure 4: Junction Capacitance

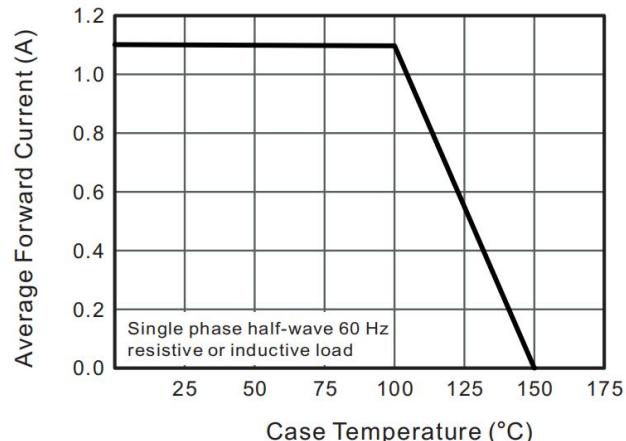
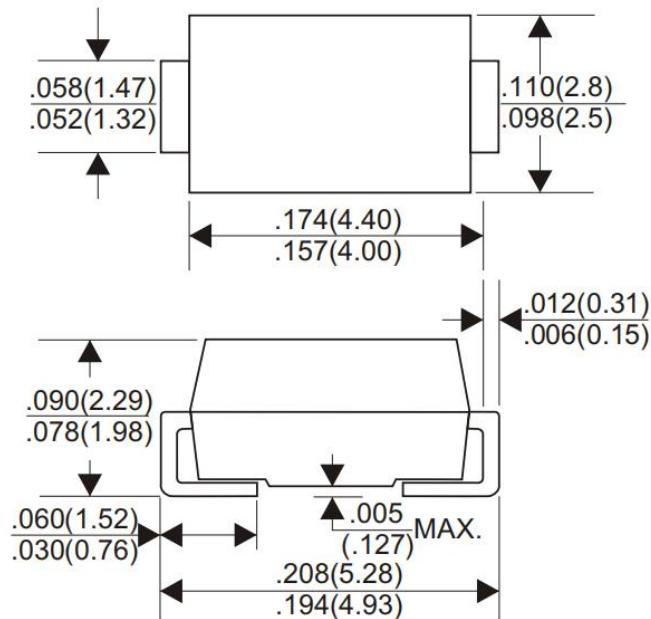


Figure 5: Forward Current Derating

■Dimension 外形封装尺寸

DO-214AC(SMA)



Dimensions in inches and (millimeters)